THYRISTORS IN PACKAGE

		$V_{drm/rrm}$, V		$I_{drm/rrm}$, μA	V_t, V	$\Delta V_{drm/rrm}$, V	P, mW
		min	max	max	max	max	max
	KP1125KN3A	7.5	9.5	150	3.5	1	250
	KP1125KN3C	14	16				
	KP1125KN3B	19	23				

		V_S, V		I_S, μA	V_F, V	V_R, V	V_{rrm}, V	I_R, μA	P, mW
		min	max	max	max	min	min	max	max
ECG6404	KY124A	6	10	500	1.5		-30	0.1	300
2N4987		6	10	500	1.5		-30	0.1	300
2N4988		7.5	9	150	1.5		-30	0.1	300
2N4990		7	9	200	1.5		-30	0.1	300
	KY121A			120	1.7	12		20	250
	KY121C					18			
	KY121B					30			
	KY120A*	6	10	120	1.7		-1.5	20	250
	KY120C*	12	16						
	KY120B*	18	24						
ECG6403*	KY503A*	±6	±10	±500	1.5			20	300
2N4991*		±6	±10	±500	1.5			20	300
2N4992*		±7.5	±9	±120	1.7			20	300
2N4993*		±7.5	±9	±250	1.7			20	300
	KY503C*	±12	±16	±120	1.7			20	250
	KY503B*	±18	±24						

SILICON EPITAXIAL PLANAR PNPN THYRISTORS (SCR'S) IN PACKAGE TO-92

TYPE	Maximum Rating							V_t, V	I_{gt}, мА	V_{gt}, V	dV/dt, V/μs	dI/dt, A/μs	t_{gt}, ns
	V_{drm}, V	V_{rrm}, V	$I_{t(rms)}$, A	$I_{t(AV)}$, A	$I_{t(sm)}$, A	V_{grm}, V	P, mW	max	max	max	min	min	max
MCR100xx* P0102xx*	200	6	0.8	0.5	7	6.0	500	1.93	0.12	0.8	25	30	200
	300												
	400												
	600												
	800												
2N5064*	200												
2N6565*	400												